



Very Low Capacitance Diode Array

This diode array is configured to protect up to two high speed data transmission lines, used in Low Voltage Differential Signal (LVDS) ports. Acting as a line terminator, minimizes overshoot and undershoot conditions

due to bus impedance as well as protect against over-voltage events as electrostatic discharges. This configuration comes in the new SOT543 package, offering a significant printed circuit board space savings compared to the SOT143.

SPECIFICATION FEATURES

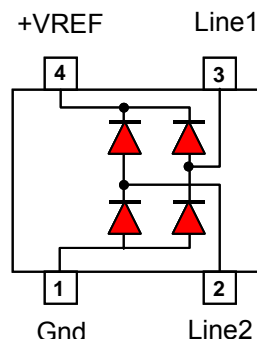
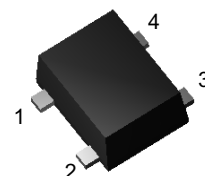
- Maximum Capacitance of 1.0pF at 0Vdc 1MHz Line-to-Ground
- Maximum Leakage Current of 1.0 μ A @ VRWM
- New SMT Package SOT543
- IEC61000-4-2 Full Compliance; 15kV Air, 8kV Contact*
- 100% Tin Matte finish (LEAD-FREE PRODUCT)
- Lead free in comply with EU RoHS 2002/95/EC directives.
- Green molding compound as per IEC61249 Std. . (Halogen Free)

APPLICATIONS

- USB 2.0 and Firewire Port Protection
- HDMI Version 1.3
- DVI



SOT543 Package



MAXIMUM RATINGS $T_j = 25^{\circ}\text{C}$ Unless otherwise noted

Rating	Symbol	Value	Units
Peak Pulse Current (8/20 μ s Waveform)	I_{PPM}	12	A
Rectifier Repetitive Peak Reverse Voltage	V_{RRM}	70	V
Operating Junction Temperature Range	T_J	-55 to +125	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^{\circ}\text{C}$
Soldering Temperature, $t_{max} = 10s$	T_L	260	$^{\circ}\text{C}$

Note: ESD Testing requires to connect a TVS between +VREF and GND, if there is no +VREF Bias connected.

**ELECTRICAL CHARACTERISTICS** $T_j = 25^{\circ}\text{C}$ unless otherwise noted

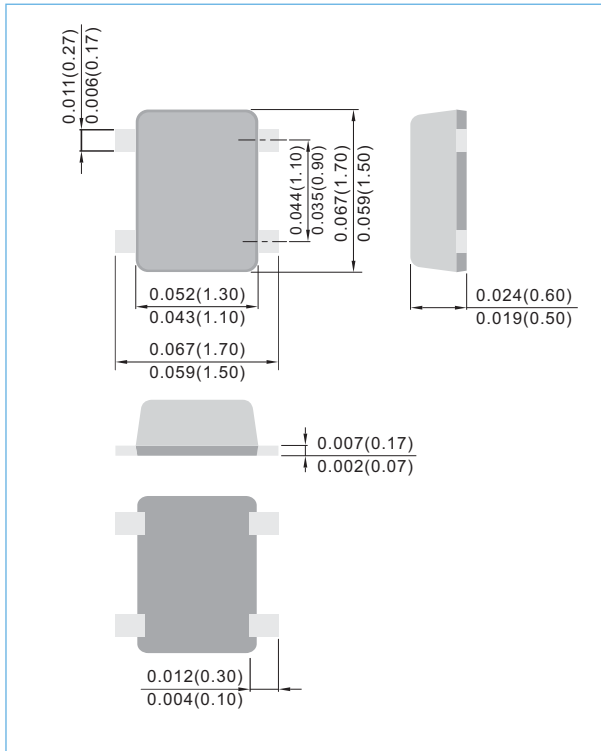
Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				70	V
Reverse Breakdown Voltage	V_{BR}	$I_{BR} = 50\mu\text{A}$	85			V
Reverse Leakage Current	I_R	$V_R = 70\text{V}$			1.0	μA
Diode Surge Forward Voltage (8/20 μs)	V_{FC}	$I_{pp} = 1\text{A}$			2.0	V
Diode Surge Forward Voltage (8/20 μs)	V_{FC}	$I_{pp} = 5\text{A}$			7.0	V
Diode Surge Forward Voltage (8/20 μs)	V_{FC}	$I_{pp} = 12\text{A}$			12	V
Off State Capacitance	C_T	0 Vdc Bias $f = 1\text{MHz}$ Between I/O Line and GND		0.8	1.0	pF
		0 Vdc Bias $f = 1\text{MHz}$ Between I/O lines		0.5	0.6	pF



PACKAGE DIMENSIONS - SOT543

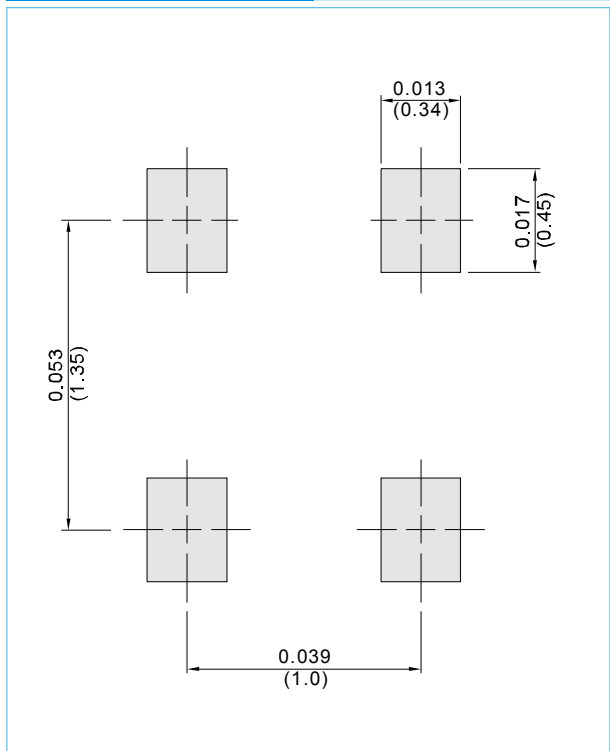
SOT-543

Unit : inch(mm)



SOT-543

Unit : inch(mm)



APPLICATION EXAMPLE

